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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

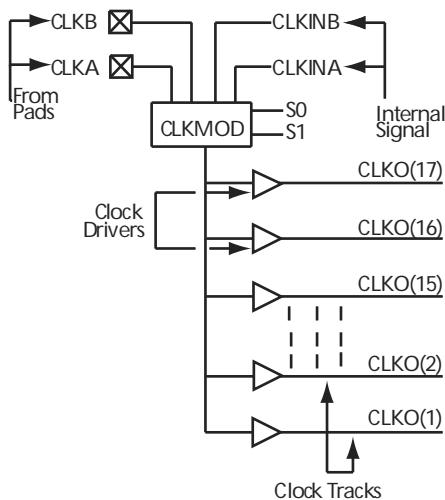
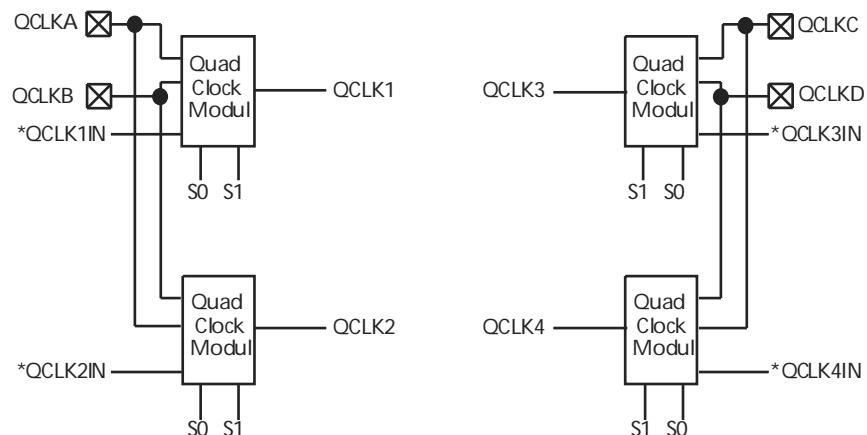
The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	2560
Number of I/O	202
Number of Gates	54000
Voltage - Supply	3V ~ 3.6V, 4.75V ~ 5.25V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	240-BFQFP
Supplier Device Package	240-PQFP (32x32)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a42mx36-2pqg240

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Figure 8 • Clock Networks of 42MX Devices**Figure 9 • Quadrant Clock Network of A42MX36 Devices**

Note: *QCLK1IN, QCLK2IN, QCLK3IN, and QCLK4IN are internally-generated signals.

3.2.5 MultiPlex I/O Modules

42MX devices feature Multiplex I/Os and support 5.0 V, 3.3 V, and mixed 3.3 V/5.0 V operations.

The MultiPlex I/O modules provide the interface between the device pins and the logic array. Figure 10, page 12 is a block diagram of the 42MX I/O module. A variety of user functions, determined by a library macro selection, can be implemented in the module. (See the *Antifuse Macro Library Guide* for more information.) All 42MX I/O modules contain tristate buffers, with input and output latches that can be configured for input, output, or bidirectional operation.

All 42MX devices contain flexible I/O structures, where each output pin has a dedicated output-enable control (Figure 10, page 12). The I/O module can be used to latch input or output data, or both, providing fast set-up time. In addition, the Designer software tools can build a D-type flip-flop using a C-module combined with an I/O module to register input and output signals. See the *Antifuse Macro Library Guide* for more details.

A42MX24 and A42MX36 devices also offer selectable PCI output drives, enabling 100% compliance with version 2.1 of the PCI specification. For low-power systems, all inputs and outputs are turned off to reduce current consumption to below 500 μ A.

To achieve 5.0 V or 3.3 V PCI-compliant output drives on A42MX24 and A42MX36 devices, a chip-wide PCI fuse is programmed via the Device Selection Wizard in the Designer software (Figure 11, page 12). When the PCI fuse is not programmed, the output drive is standard.

3.3.7 Low Power Mode

42MX devices have been designed with a Low Power Mode. This feature, activated with setting the special LP pin to HIGH for a period longer than 800 ns, is particularly useful for battery-operated systems where battery life is a primary concern. In this mode, the core of the device is turned off and the device consumes minimal power with low standby current. In addition, all input buffers are turned off, and all outputs and bidirectional buffers are tristated. Since the core of the device is turned off, the states of the registers are lost. The device must be re-initialized when exiting Low Power Mode. I/Os can be driven during LP mode, and clock pins should be driven HIGH or LOW and should not float to avoid drawing current. To exit LP mode, the LP pin must be pulled LOW for over 200 μ s to allow for charge pumps to power up, and device initialization will begin.

3.4 Power Dissipation

The general power consumption of MX devices is made up of static and dynamic power and can be expressed with the following equation.

3.4.1 General Power Equation

$$P = [ICC_{\text{standby}} + ICC_{\text{active}}] * V_{CC1} + I_{OL} * V_{OL} * N + I_{OH} * (V_{CC1} - V_{OH}) * M$$

EQ 1

where:

- ICC_{standby} is the current flowing when no inputs or outputs are changing.
- ICC_{active} is the current flowing due to CMOS switching.
- I_{OL} , I_{OH} are TTL sink/source currents.
- V_{OL} , V_{OH} are TTL level output voltages.
- N equals the number of outputs driving TTL loads to V_{OL} .
- M equals the number of outputs driving TTL loads to V_{OH} .

Accurate values for N and M are difficult to determine because they depend on the family type, on design details, and on the system I/O. The power can be divided into two components: static and active.

3.4.2 Static Power Component

The static power due to standby current is typically a small component of the overall power consumption. Standby power is calculated for commercial, worst-case conditions. The static power dissipation by TTL loads depends on the number of outputs driving, and on the DC load current. For instance, a 32-bit bus sinking 4mA at 0.33V will generate 42mW with all outputs driving LOW, and 140mW with all outputs driving HIGH. The actual dissipation will average somewhere in between, as I/Os switch states with time.

3.4.3 Active Power Component

Power dissipation in CMOS devices is usually dominated by the dynamic power dissipation. Dynamic power consumption is frequency-dependent and is a function of the logic and the external I/O. Active power dissipation results from charging internal chip capacitances of the interconnect, unprogrammed antifuses, module inputs, and module outputs, plus external capacitances due to PC board traces and load device inputs. An additional component of the active power dissipation is the totem pole current in the CMOS transistor pairs. The net effect can be associated with an equivalent capacitance that can be combined with frequency and voltage to represent active power dissipation.

The power dissipated by a CMOS circuit can be expressed by the equation:

$$\text{Power}(\mu\text{W}) = C_{EQ} * V_{CCA2}^2 * F(1)$$

EQ 2

where:

- C_{EQ} = Equivalent capacitance expressed in picofarads (pF)

Table 33 • Timing Parameters for 33 MHz PCI

Symbol	Parameter	PCI		A42MX24		A42MX36		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
$t_{SU(PTP)}$	Input Set-Up Time to CLK—Point-to-Point	10, 12 ²	–	1.5	–	1.5	–	ns
t_H	Input Hold to CLK	0	–	0	–	0	–	ns

1. TOFF is system dependent. MX PCI devices have 7.4 ns turn-off time, reflection is typically an additional 10 ns.
2. REQ# and GNT# are point-to-point signals and have different output valid delay and input setup times than do bussed signals. GNT# has a setup of 10; REW# has a setup of 12.

3.11.6.1 Timing Characteristics

The following tables list the timing characteristics.

**Table 34 • A40MX02 Timing Characteristics (Nominal 5.0 V Operation)
(Worst-Case Commercial Conditions, VCC = 4.75 V, T_J = 70°C)**

Parameter / Description	–3 Speed		–2 Speed		–1 Speed		Std Speed		–F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Propagation Delays											
t_{PD1}	Single Module	1.2	1.4	1.6	1.9	2.7	ns				
t_{PD2}	Dual-Module Macros	2.7	3.1	3.5	4.1	5.7	ns				
t_{CO}	Sequential Clock-to-Q	1.2	1.4	1.6	1.9	2.7	ns				
t_{GO}	Latch G-to-Q	1.2	1.4	1.6	1.9	2.7	ns				
t_{RS}	Flip-Flop (Latch) Reset-to-Q	1.2	1.4	1.6	1.9	2.7	ns				
Logic Module Predicted Routing Delays¹											
t_{RD1}	FO = 1 Routing Delay	1.3	1.5	1.7	2.0	2.8	ns				
t_{RD2}	FO = 2 Routing Delay	1.8	2.1	2.4	2.8	3.9	ns				
t_{RD3}	FO = 3 Routing Delay	2.3	2.7	3.0	3.6	5.0	ns				
t_{RD4}	FO = 4 Routing Delay	2.9	3.3	3.7	4.4	6.1	ns				
t_{RD8}	FO = 8 Routing Delay	4.9	5.7	6.5	7.6	10.6	ns				
Logic Module Sequential Timing²											
t_{SUD}	Flip-Flop (Latch) Data Input Set-Up	3.1	3.5	4.0	4.7	6.6	ns				
t_{HD}^3	Flip-Flop (Latch) Data Input Hold	0.0	0.0	0.0	0.0	0.0	ns				
t_{SUENA}	Flip-Flop (Latch) Enable Set-Up	3.1	3.5	4.0	4.7	6.6	ns				
t_{HEN}	Flip-Flop (Latch) Enable Hold	0.0	0.0	0.0	0.0	0.0	ns				
t_{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.3	3.8	4.3	5.0	7.0	ns				
t_{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	3.3	3.8	4.3	5.0	7.0	ns				
t_A	Flip-Flop Clock Input Period	4.8	5.6	6.3	7.5	10.4	ns				
f_{MAX}	Flip-Flop (Latch) Clock Frequency (FO = 128)	181	168	154	134	80	MHz				

Table 34 • A40MX02 Timing Characteristics (Nominal 5.0 V Operation) (continued)
(Worst-Case Commercial Conditions, VCC = 4.75 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
TTL Output Module Timing⁴											
t _{DLH}	Data-to-Pad HIGH	3.3	3.8	4.3	5.1	7.2	ns				
t _{DHL}	Data-to-Pad LOW	4.0	4.6	5.2	6.1	8.6	ns				
t _{ENZH}	Enable Pad Z to HIGH	3.7	4.3	4.9	5.8	8.0	ns				
t _{ENZL}	Enable Pad Z to LOW	4.7	5.4	6.1	7.2	10.1	ns				
t _{ENHZ}	Enable Pad HIGH to Z	7.9	9.1	10.4	12.2	17.1	ns				
t _{ENLZ}	Enable Pad LOW to Z	5.9	6.8	7.7	9.0	12.6	ns				
d _{TLH}	Delta LOW to HIGH	0.02	0.02	0.03	0.03	0.04	ns/pF				
d _{THL}	Delta HIGH to LOW	0.03	0.03	0.03	0.04	0.06	ns/pF				
CMOS Output Module Timing⁴											
t _{DLH}	Data-to-Pad HIGH	3.9	4.5	5.1	6.05	8.5	ns				
t _{DHL}	Data-to-Pad LOW	3.4	3.9	4.4	5.2	7.3	ns				
t _{ENZH}	Enable Pad Z to HIGH	3.4	3.9	4.4	5.2	7.3	ns				
t _{ENZL}	Enable Pad Z to LOW	4.9	5.6	6.4	7.5	10.5	ns				
t _{ENHZ}	Enable Pad HIGH to Z	7.9	9.1	10.4	12.2	17.0	ns				
t _{ENLZ}	Enable Pad LOW to Z	5.9	6.8	7.7	9.0	12.6	ns				
d _{TLH}	Delta LOW to HIGH	0.03	0.04	0.04	0.05	0.07	ns/pF				
d _{THL}	Delta HIGH to LOW	0.02	0.02	0.03	0.03	0.04	ns/pF				

1. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance
2. Set-up times assume fanout of 3. Further testing information can be obtained from the Timer utility
3. The hold time for the DFME1A macro may be greater than 0 ns. Use the Timer tool from the Designer software to check the hold time for this macro.
4. Delays based on 35pF loading

Table 35 • A40MX02 Timing Characteristics (Nominal 3.3 V Operation)
(Worst-Case Commercial Conditions, VCC = 3.0 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Propagation Delays											
t _{PD1}	Single Module	1.7	2.0	2.3	2.7	3.7	ns				
t _{PD2}	Dual-Module Macros	3.7	4.3	4.9	5.7	8.0	ns				
t _{CO}	Sequential Clock-to-Q	1.7	2.0	2.3	2.7	3.7	ns				
t _{GO}	Latch G-to-Q	1.7	2.0	2.3	2.7	3.7	ns				
t _{RS}	Flip-Flop (Latch) Reset-to-Q	1.7	2.0	2.3	2.7	3.7	ns				
Logic Module Predicted Routing Delays¹											

Table 35 • A40MX02 Timing Characteristics (Nominal 3.3 V Operation) (continued)
(Worst-Case Commercial Conditions, VCC = 3.0 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t _{RD1}	FO = 1 Routing Delay		2.0		2.2		2.5		3.0		4.2 ns
t _{RD2}	FO = 2 Routing Delay		2.7		3.1		3.5		4.1		5.7 ns
t _{RD3}	FO = 3 Routing Delay		3.4		3.9		4.4		5.2		7.3 ns
t _{RD4}	FO = 4 Routing Delay		4.2		4.8		5.4		6.3		8.9 ns
t _{RD8}	FO = 8 Routing Delay		7.1		8.2		9.2		10.9		15.2 ns
Logic Module Sequential Timing²											
t _{SUD}	Flip-Flop (Latch) Data Input Set-Up		4.3		4.9		5.6		6.6		9.2 ns
t _{HD} ³	Flip-Flop (Latch) Data Input Hold		0.0		0.0		0.0		0.0		ns
t _{SUENA}	Flip-Flop (Latch) Enable Set-Up	4.3		4.9		5.6		6.6		9.2	ns
t _{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width		4.6		5.3		6.0		7.0		9.8 ns
t _{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width		4.6		5.3		6.0		7.0		9.8 ns
t _A	Flip-Flop Clock Input Period	6.8		7.8		8.9		10.4		14.6	ns
f _{MAX}	Flip-Flop (Latch) Clock Frequency (FO = 128)		109		101		92		80		48 MHz
Input Module Propagation Delays											
t _{INYH}	Pad-to-Y HIGH		1.0		1.1		1.3		1.5		2.1 ns
t _{INYL}	Pad-to-Y LOW		0.9		1.0		1.1		1.3		1.9 ns
Input Module Predicted Routing Delays¹											
t _{IRD1}	FO = 1 Routing Delay		2.9		3.4		3.8		4.5		6.3 ns
t _{IRD2}	FO = 2 Routing Delay		3.6		4.2		4.8		5.6		7.8 ns
t _{IRD3}	FO = 3 Routing Delay		4.4		5.0		5.7		6.7		9.4 ns
t _{IRD4}	FO = 4 Routing Delay		5.1		5.9		6.7		7.8		11.0 ns
t _{IRD8}	FO = 8 Routing Delay		8.0		9.26		10.5		12.6		17.3 ns
Global Clock Network											
t _{CKH}	Input LOW to HIGH FO = 16		6.4		7.4		8.3		9.8		13.7 ns
	FO = 128		6.4		7.4		8.3		9.8		13.7
t _{CKL}	Input HIGH to LOW FO = 16		6.7		7.8		8.8		10.4		14.5 ns
	FO = 128		6.7		7.8		8.8		10.4		14.5
t _{PWH}	Minimum Pulse Width HIGH	FO = 16	3.1		3.6		4.1		4.8		6.7 ns
	FO = 128		3.3		3.8		4.3		5.1		7.1
t _{PWL}	Minimum Pulse Width LOW	FO = 16	3.1		3.6		4.1		4.8		6.7 ns
	FO = 128		3.3		3.8		4.3		5.1		7.1
t _{CKSW}	Maximum Skew	FO = 16	0.6		0.6		0.7		0.8		1.2 ns
	FO = 128		0.8		0.9		1.0		1.2		1.6

Table 38 • A42MX09 Timing Characteristics (Nominal 5.0 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 4.75 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
CMOS Output Module Timing⁵											
t _{DLH}	Data-to-Pad HIGH		2.4		2.7		3.1		3.6		5.1 ns
t _{DHL}	Data-to-Pad LOW		2.9		3.2		3.6		4.3		6.0 ns
t _{ENZH}	Enable Pad Z to HIGH		2.7		2.9		3.3		3.9		5.5 ns
t _{ENZL}	Enable Pad Z to LOW		2.9		3.2		3.7		4.3		6.1 ns
t _{ENHZ}	Enable Pad HIGH to Z		4.9		5.4		6.2		7.3		10.2 ns
t _{ENLZ}	Enable Pad LOW to Z		5.3		5.9		6.7		7.9		11.1 ns
t _{GLH}	G-to-Pad HIGH		4.2		4.6		5.2		6.1		8.6 ns
t _{GHL}	G-to-Pad LOW		4.2		4.6		5.2		6.1		8.6 ns
t _{LSU}	I/O Latch Set-Up	0.5		0.5		0.6		0.7		1.0	ns
t _{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		5.2		5.8		6.6		7.7		10.8 ns
t _{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		7.4		8.2		9.3		10.9		15.3 ns
d _{TLH}	Capacity Loading, LOW to HIGH	0.03		0.03		0.03		0.04		0.06	ns/pF
d _{THL}	Capacity Loading, HIGH to LOW	0.04		0.04		0.04		0.05		0.07	ns/pF

- For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.
- Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.
- Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.
- Set-up and hold timing parameters for the input buffer latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.
- Delays based on 35 pF loading

Table 39 • A42MX09 Timing Characteristics (Nominal 3.3 V Operation) (Worst-Case Commercial Conditions, VCCA = 3.0 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Propagation Delays¹											
t _{PD1}	Single Module	1.6		1.8		2.1		2.5		3.5	ns
t _{CO}	Sequential Clock-to-Q	1.8		2.0		2.3		2.7		3.8	ns
t _{GO}	Latch G-to-Q	1.7		1.9		2.1		2.5		3.5	ns
t _{RS}	Flip-Flop (Latch) Reset-to-Q	2.0		2.2		2.5		2.9		4.1	ns
Logic Module Predicted Routing Delays²											
t _{RD1}	FO = 1 Routing Delay	1.0		1.1		1.2		1.4		2.0	ns
t _{RD2}	FO = 2 Routing Delay	1.3		1.4		1.6		1.9		2.7	ns
t _{RD3}	FO = 3 Routing Delay	1.6		1.8		2.0		2.4		3.3	ns

Table 39 • A42MX09 Timing Characteristics (Nominal 3.3 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 3.0 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
CMOS Output Module Timing⁵											
t _{D LH}	Data-to-Pad HIGH		3.4		3.8		5.5		6.4		9.0 ns
t _{D HL}	Data-to-Pad LOW		4.1		4.5		4.2		5.0		7.0 ns
t _{ENZH}	Enable Pad Z to HIGH		3.7		4.1		4.6		5.5		7.6 ns
t _{ENZL}	Enable Pad Z to LOW		4.1		4.5		5.1		6.1		8.5 ns
t _{ENHZ}	Enable Pad HIGH to Z		6.9		7.6		8.6		10.2		14.2 ns
t _{ENLZ}	Enable Pad LOW to Z		7.5		8.3		9.4		11.1		15.5 ns
t _{GLH}	G-to-Pad HIGH		5.8		6.5		7.3		8.6		12.0 ns
t _{GHL}	G-to-Pad LOW		5.8		6.5		7.3		8.6		12.0 ns
t _{LSU}	I/O Latch Set-Up	0.7		0.8		0.9		1.0		1.4	ns
t _{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.7		9.7		10.9		12.9		18.0 ns
t _{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		12.2		13.5		15.4		18.1		25.3 ns
d _{TLH}	Capacity Loading, LOW to HIGH	0.04		0.04		0.05		0.06		0.08	ns/pF
d _{THL}	Capacity Loading, HIGH to LOW	0.05		0.05		0.06		0.07		0.10	ns/pF

- For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.
- Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.
- Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.
- Set-up and hold timing parameters for the input buffer latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.
- Delays based on 35 pF loading.

Table 40 • A42MX16 Timing Characteristics (Nominal 5.0 V Operation) (Worst-Case Commercial Conditions, VCCA = 4.75 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Propagation Delays¹											
t _{PD1}	Single Module	1.4		1.5		1.7		2.0		2.8	ns
t _{CO}	Sequential Clock-to-Q	1.4		1.6		1.8		2.1		3.0	ns
t _{GO}	Latch G-to-Q	1.4		1.5		1.7		2.0		2.8	ns
t _{RS}	Flip-Flop (Latch) Reset-to-Q	1.6		1.7		2.0		2.3		3.3	ns
Logic Module Predicted Routing Delays²											
t _{RD1}	FO = 1 Routing Delay	0.8		0.9		1.0		1.2		1.6	ns
t _{RD2}	FO = 2 Routing Delay	1.0		1.2		1.3		1.5		2.1	ns

Table 41 • A42MX16 Timing Characteristics (Nominal 3.3 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 3.0 V, TJ = 70°C)

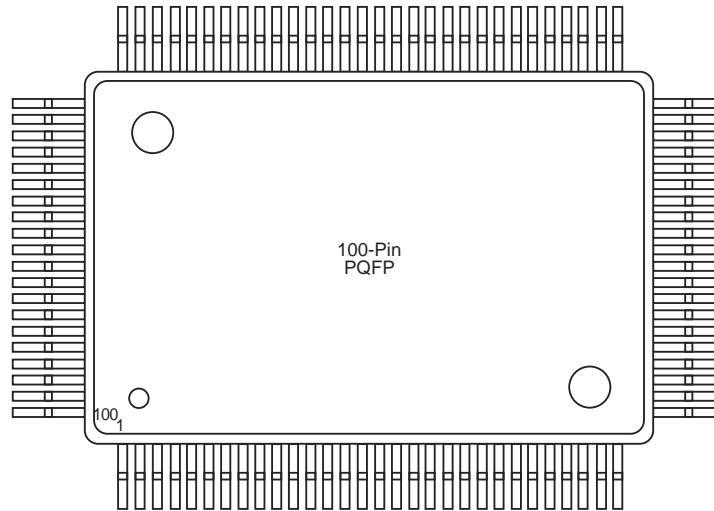
Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Sequential Timing^{3, 4}											
t _{SUD}	Flip-Flop (Latch) Data Input Set-Up	0.5	0.5	0.6	0.7	0.9					ns
t _{HD}	Flip-Flop (Latch) Data Input Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{SUENA}	Flip-Flop (Latch) Enable Set-Up	1.0	1.1	1.2	1.4	2.0					ns
t _{HENA}	Flip-Flop (Latch) Enable Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.8	5.3	6.0	7.1	9.9					ns
t _{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	6.2	6.9	7.9	9.2	12.9					ns
t _A	Flip-Flop Clock Input Period	9.5	10.6	12.0	14.1	19.8					ns
t _{IINH}	Input Buffer Latch Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{INSU}	Input Buffer Latch Set-Up	0.7	0.8	0.9	1.01	1.4					ns
t _{OUTH}	Output Buffer Latch Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{OUTSU}	Output Buffer Latch Set-Up	0.7	0.8	0.89	1.01	1.4					ns
f _{MAX}	Flip-Flop (Latch) Clock Frequency	129	117	108	94	56	MHz				
Input Module Propagation Delays											
t _{IINYH}	Pad-to-Y HIGH	1.5	1.6	1.9	2.2	3.1	ns				
t _{IINYL}	Pad-to-Y LOW	1.1	1.3	1.4	1.7	2.4	ns				
t _{INGH}	G to Y HIGH	2.0	2.2	2.5	2.9	4.1	ns				
t _{INGL}	G to Y LOW	2.0	2.2	2.5	2.9	4.1	ns				
Input Module Predicted Routing Delays²											
t _{IRD1}	FO = 1 Routing Delay	2.6	2.9	3.2	3.8	5.3	ns				
t _{IRD2}	FO = 2 Routing Delay	2.9	3.2	3.7	4.3	6.1	ns				
t _{IRD3}	FO = 3 Routing Delay	3.3	3.6	4.1	4.9	6.8	ns				
t _{IRD4}	FO = 4 Routing Delay	3.6	4.0	4.6	5.4	7.6	ns				
t _{IRD8}	FO = 8 Routing Delay	5.1	5.6	6.4	7.5	10.5	ns				
Global Clock Network											
t _{CKH}	Input LOW to HIGH	FO = 32	4.4	4.8	5.5	6.5	9.0	ns			
		FO = 384	4.8	5.3	6.0	7.1	9.9	ns			
t _{CKL}	Input HIGH to LOW	FO = 32	5.3	5.9	6.7	7.8	11.0	ns			
		FO = 384	6.2	6.9	7.9	9.2	12.9	ns			
t _{PWH}	Minimum Pulse Width HIGH	FO = 32	5.7	6.3	7.1	8.4	11.8	ns			
		FO = 384	6.6	7.4	8.3	9.8	13.7	ns			

Table 42 • A42MX24 Timing Characteristics (Nominal 5.0 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 4.75 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Input Module Propagation Delays											
t _{INPY}	Input Data Pad-to-Y		1.0		1.1		1.3		1.5		2.1 ns
t _{INGO}	Input Latch Gate-to-Output		1.3		1.4		1.6		1.9		2.6 ns
t _{INH}	Input Latch Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{INSU}	Input Latch Set-Up	0.5		0.5		0.6		0.7		1.0	ns
t _{ILA}	Latch Active Pulse Width	4.7		5.2		5.9		6.9		9.7	ns

Table 49 • PL84

PL84	Pin Number	A40MX04 Function	A42MX09 Function	A42MX16 Function	A42MX24 Function
84	I/O	VCCA	VCCA	VCCA	VCCA

Figure 41 • PQ100**Table 50 • PQ 100**

PQ100	Pin Number	A40MX02 Function	A40MX04 Function	A42MX09 Function	A42MX16 Function
1	NC	NC	I/O	I/O	
2	NC	NC	DCLK, I/O	DCLK, I/O	
3	NC	NC	I/O	I/O	
4	NC	NC	MODE	MODE	
5	NC	NC	I/O	I/O	
6	PRB, I/O	PRB, I/O	I/O	I/O	
7	I/O	I/O	I/O	I/O	
8	I/O	I/O	I/O	I/O	
9	I/O	I/O	GND	GND	
10	I/O	I/O	I/O	I/O	
11	I/O	I/O	I/O	I/O	
12	I/O	I/O	I/O	I/O	
13	GND	GND	I/O	I/O	
14	I/O	I/O	I/O	I/O	
15	I/O	I/O	I/O	I/O	
16	I/O	I/O	VCCA	VCCA	
17	I/O	I/O	VCCI	VCCI	
18	I/O	I/O	I/O	I/O	

Table 50 • PQ 100

PQ100	Pin Number	A40MX02 Function	A40MX04 Function	A42MX09 Function	A42MX16 Function
56	VCC	VCC	I/O	I/O	
57	I/O	I/O	GND	GND	
58	I/O	I/O	I/O	I/O	
59	I/O	I/O	I/O	I/O	
60	I/O	I/O	I/O	I/O	
61	I/O	I/O	I/O	I/O	
62	I/O	I/O	I/O	I/O	
63	GND	GND	I/O	I/O	
64	I/O	I/O	LP	LP	
65	I/O	I/O	VCCA	VCCA	
66	I/O	I/O	VCCI	VCCI	
67	I/O	I/O	VCCA	VCCA	
68	I/O	I/O	I/O	I/O	
69	VCC	VCC	I/O	I/O	
70	I/O	I/O	I/O	I/O	
71	I/O	I/O	I/O	I/O	
72	I/O	I/O	GND	GND	
73	I/O	I/O	I/O	I/O	
74	I/O	I/O	I/O	I/O	
75	I/O	I/O	I/O	I/O	
76	I/O	I/O	I/O	I/O	
77	NC	NC	I/O	I/O	
78	NC	NC	I/O	I/O	
79	NC	NC	SDI, I/O	SDI, I/O	
80	NC	I/O	I/O	I/O	
81	NC	I/O	I/O	I/O	
82	NC	I/O	I/O	I/O	
83	I/O	I/O	I/O	I/O	
84	I/O	I/O	GND	GND	
85	I/O	I/O	I/O	I/O	
86	GND	GND	I/O	I/O	
87	GND	GND	PRA, I/O	PRA, I/O	
88	I/O	I/O	I/O	I/O	
89	I/O	I/O	CLKA, I/O	CLKA, I/O	
90	CLK, I/O	CLK, I/O	VCCA	VCCA	
91	I/O	I/O	I/O	I/O	
92	MODE	MODE	CLKB, I/O	CLKB, I/O	

Table 52 • PQ160

PQ160	Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Function
	21	CLKA, I/O	CLKA, I/O	CLKA, I/O
	22	I/O	I/O	I/O
	23	PRA, I/O	PRA, I/O	PRA, I/O
	24	NC	I/O	WD, I/O
	25	I/O	I/O	WD, I/O
	26	I/O	I/O	I/O
	27	I/O	I/O	I/O
	28	NC	I/O	I/O
	29	I/O	I/O	WD, I/O
	30	GND	GND	GND
	31	NC	I/O	WD, I/O
	32	I/O	I/O	I/O
	33	I/O	I/O	I/O
	34	I/O	I/O	I/O
	35	NC	VCCI	VCCI
	36	I/O	I/O	WD, I/O
	37	I/O	I/O	WD, I/O
	38	SDI, I/O	SDI, I/O	SDI, I/O
	39	I/O	I/O	I/O
	40	GND	GND	GND
	41	I/O	I/O	I/O
	42	I/O	I/O	I/O
	43	I/O	I/O	I/O
	44	GND	GND	GND
	45	I/O	I/O	I/O
	46	I/O	I/O	I/O
	47	I/O	I/O	I/O
	48	I/O	I/O	I/O
	49	GND	GND	GND
	50	I/O	I/O	I/O
	51	I/O	I/O	I/O
	52	NC	I/O	I/O
	53	I/O	I/O	I/O
	54	NC	VCCA	VCCA
	55	I/O	I/O	I/O
	56	I/O	I/O	I/O
	57	VCCA	VCCA	VCCA

Table 54 • PQ240

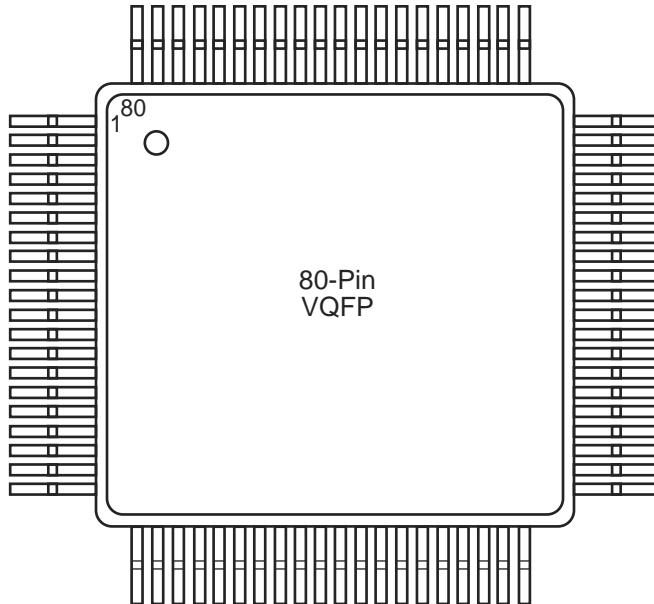
PQ240	
Pin Number	A42MX36 Function
52	VCCI
53	I/O
54	WD, I/O
55	WD, I/O
56	I/O
57	SDI, I/O
58	I/O
59	VCCA
60	GND
61	GND
62	I/O
63	I/O
64	I/O
65	I/O
66	I/O
67	I/O
68	I/O
69	I/O
70	I/O
71	VCCI
72	I/O
73	I/O
74	I/O
75	I/O
76	I/O
77	I/O
78	I/O
79	I/O
80	I/O
81	I/O
82	I/O
83	I/O
84	I/O
85	VCCA
86	I/O
87	I/O
88	VCCA

Table 54 • PQ240

PQ240	
Pin Number	A42MX36 Function
200	I/O
201	I/O
202	I/O
203	I/O
204	I/O
205	I/O
206	VCCA
207	I/O
208	I/O
209	VCCA
210	VCCI
211	I/O
212	I/O
213	I/O
214	I/O
215	I/O
216	I/O
217	I/O
218	I/O
219	VCCA
220	I/O
221	I/O
222	I/O
223	I/O
224	I/O
225	I/O
226	I/O
227	VCCI
228	I/O
229	I/O
230	I/O
231	I/O
232	I/O
233	I/O
234	I/O
235	I/O
236	I/O

Table 54 • PQ240

PQ240	
Pin Number	A42MX36 Function
237	GND
238	MODE
239	VCCA
240	GND

Figure 46 • VQ80**Table 55 • VQ80**

VQ80		
Pin Number	A40MX02 Function	A40MX04 Function
1	I/O	I/O
2	NC	I/O
3	NC	I/O
4	NC	I/O
5	I/O	I/O
6	I/O	I/O
7	GND	GND
8	I/O	I/O
9	I/O	I/O
10	I/O	I/O
11	I/O	I/O
12	I/O	I/O

Table 55 • VQ80

VQ80		
Pin Number	A40MX02 Function	A40MX04 Function
49	I/O	I/O
50	CLK, I/O	CLK, I/O
51	I/O	I/O
52	MODE	MODE
53	VCC	VCC
54	NC	I/O
55	NC	I/O
56	NC	I/O
57	SDI, I/O	SDI, I/O
58	DCLK, I/O	DCLK, I/O
59	PRA, I/O	PRA, I/O
60	NC	NC
61	PRB, I/O	PRB, I/O
62	I/O	I/O
63	I/O	I/O
64	I/O	I/O
65	I/O	I/O
66	I/O	I/O
67	I/O	I/O
68	GND	GND
69	I/O	I/O
70	I/O	I/O
71	I/O	I/O
72	I/O	I/O
73	I/O	I/O
74	VCC	VCC
75	I/O	I/O
76	I/O	I/O
77	I/O	I/O
78	I/O	I/O
79	I/O	I/O
80	I/O	I/O

Table 58 • CQ208

CQ208	
Pin Number	A42MX36 Function
1	GND
2	VCCA
3	MODE
4	I/O
5	I/O
6	I/O
7	I/O
8	I/O
9	I/O
10	I/O
11	I/O
12	I/O
13	I/O
14	I/O
15	I/O
16	I/O
17	VCCA
18	I/O
19	I/O
20	I/O
21	I/O
22	GND
23	I/O
24	I/O
25	I/O
26	I/O
27	GND
28	VCCI
29	VCCA
30	I/O
31	I/O
32	VCCA
33	I/O
34	I/O
35	I/O
36	I/O

Table 61 • PG132

PG132	
Pin Number	A42MX09 Function
B3	I/O
A2	I/O
C3	DCLK
B5	GNDA
E12	GNDA
J2	GNDA
M9	GNDA
B9	GNDI
C5	GNDI
E11	GNDI
F4	GNDI
J3	GNDI
J11	GNDI
L5	GNDI
L9	GNDI
C9	GNDQ
E3	GNDQ
K12	GNDQ
D7	VCCA
G3	VCCA
G10	VCCA
L7	VCCA
C7	VCCI
G2	VCCI
G11	VCCI
K7	VCCI

Table 62 • CQ172

99	I/O
100	I/O
101	I/O
102	I/O
103	GND
104	I/O
105	I/O
106	VKS
107	VPP
108	GND
109	VCCI
110	VSV
111	I/O
112	I/O
113	VCC
114	I/O
115	I/O
116	I/O
117	I/O
118	GND
119	I/O
120	I/O
121	I/O
122	I/O
123	GNDI
124	I/O
125	I/O
126	I/O
127	I/O
128	I/O
129	I/O
130	I/O
131	SDI
132	I/O
133	I/O
134	I/O
135	I/O
136	VCCI
137	I/O